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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DATA SHEET

74ALVT16244

2.5V/3.3V 16-bit buffer/driver (3-State)

Product specification
Supersedes data of 1998 Feb 13
IC23 Data Handbook

1998 Oct 07

2.5V/3.3V 16-bit buffer/driver (3-State)

74ALVT16244

FEATURES

- 16-bit bus interface
- 5V I/O compatible
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

DESCRIPTION

The 74ALVT16244 is a high-performance BiCMOS product designed for V_{CC} operation at 2.5V or 3.3V with I/O compatibility up to 5V.

This device is a 16-bit buffer and line driver featuring non-inverting 3-State bus outputs. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer.

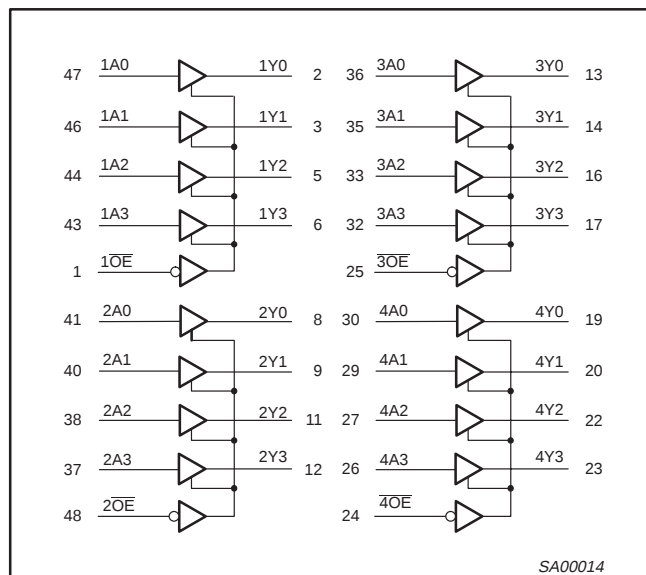
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25^{\circ}\text{C}$	TYPICAL		UNIT
			2.5V	3.3V	
t_{PLH} t_{PHL}	Propagation delay nAx to nYx	$C_L = 50\text{pF}$	1.8 1.9	1.5 1.5	ns
C_{IN}	Input capacitance DIR, OE	$V_I = 0\text{V}$ or V_{CC}	3	3	pF
C_{Out}	Output capacitance	$V_{IO} = 0\text{V}$ or V_{CC}	9	9	pF
I_{CCZ}	Total supply current	Outputs disabled	40	70	μA

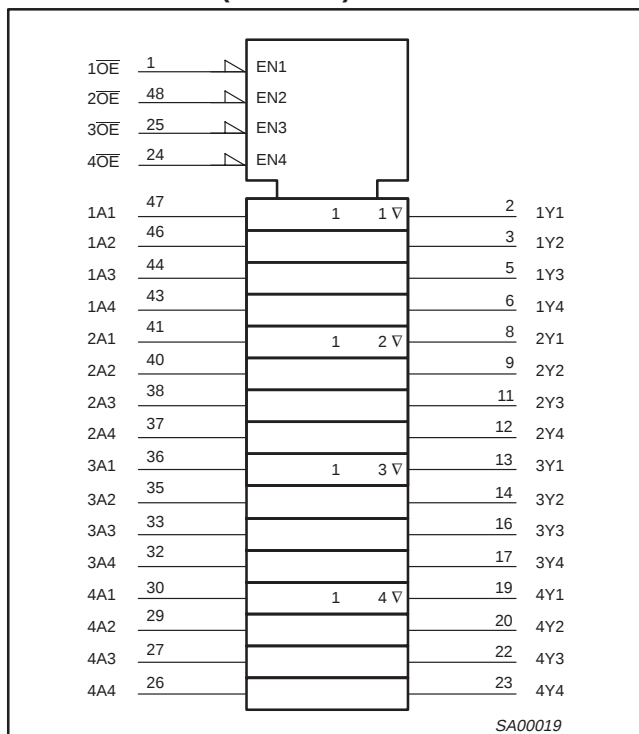
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to $+85^{\circ}\text{C}$	74ALVT16244 DL	AV16244 DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to $+85^{\circ}\text{C}$	74ALVT16244 DGG	AV16244 DGG	SOT362-1

LOGIC SYMBOL



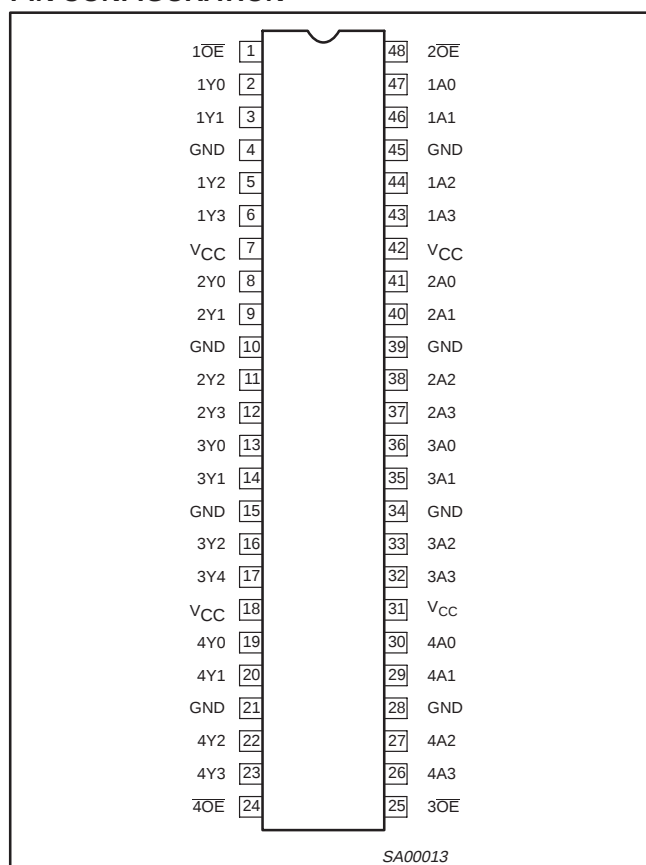
LOGIC SYMBOL (IEEE/IEC)



2.5V/3.3V 16-bit buffer/driver (3-State)

74ALVT16244

PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43 41, 40, 38, 37 36, 35, 33, 32 30, 29, 27, 26	1A0 - 1A3, 2A0 - 2A3, 3A0 - 3A3, 4A0 - 4A3	Data inputs
2, 3, 5, 6 8, 9, 11, 12 13, 14, 16, 17 19, 20, 22, 23	1Y0 - 1Y3, 2Y0 - 2Y3, 3Y0 - 3Y3, 4Y0 - 4Y3	Data outputs
1, 48 25, 24	1OE, 2OE, 3OE, 4OE	Output enables
4, 10, 15, 21 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage

FUNCTION TABLE

INPUTS		OUTPUTS
nOE	nAx	nYx
L	L	L
L	H	H
H	X	Z

H = High voltage level

L = Low voltage level

X = Don't care

Z = High Impedance "off" state

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
V _I	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
I _{OUT}	DC output current	Output in Low state	128	mA
		Output in High state	-64	
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

2.5V/3.3V 16-bit buffer/driver (3-State)

74ALVT16244

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	2.5V RANGE LIMITS		3.3V RANGE LIMITS		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	DC supply voltage	2.3	2.7	3.0	3.6	V
V_I	Input voltage	0	5.5	0	5.5	V
V_{IH}	High-level input voltage	1.7		2.0		V
V_{IL}	Input voltage		0.7		0.8	V
I_{OH}	High-level output current		-8		-32	mA
I_{OL}	Low-level output current		8		32	mA
	Low-level output current; current duty cycle $\leq 50\%$; $f \geq 1$ kHz		24		64	
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10		10	ns/V
T_{amb}	Operating free-air temperature range	-40	+85	-40	+85	°C

DC ELECTRICAL CHARACTERISTICS (3.3V $\pm$ 0.3V RANGE)

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS			UNIT
				Temp = -40°C to +85°C			
				MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	V _{CC} = 3.0V; I _{IK} = -18mA			-0.85	-1.2	V
V _{OH}	High-level output voltage	V _{CC} = 3.0 to 3.6V; I _{OH} = -100μA		V _{CC} -0.2	V _{CC}		V
		V _{CC} = 3.0V; I _{OH} = -32mA		2.0	2.3		
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 100μA			0.07	0.2	V
		V _{CC} = 3.0V; I _{OL} = 16mA			0.25	0.4	
		V _{CC} = 3.0V; I _{OL} = 32mA			0.3	0.5	
		V _{CC} = 3.0V; I _{OL} = 64mA			0.4	0.55	
I _I	Input leakage current	V _{CC} = 3.6V; V _I = V _{CC} or GND	Control pins		0.1	±1	μA
		V _{CC} = 0 or 3.6V; V _I = 5.5V			01.	10	
		V _{CC} = 3.6V; V _I = V _{CC}	Data pins ⁴		0.5	1	
		V _{CC} = 3.6V; V _I = 0V			0.1	-5	
I _{OFF}	Off current	V _{CC} = 0V; V _I or V _O = 0 to 4.5V			0.1	±100	μA
I _{HOLD}	Bus Hold current Data inputs ⁶	V _{CC} = 3V; V _I = 0.8V		75	130		μA
		V _{CC} = 3V; V _I = 2.0V		-75	-140		
		V _{CC} = 0V to 3.6V; V _{CC} = 3.6V		±500			
I _{EX}	Current into an output in the High state when V _O > V _{CC}	V _O = 5.5V; V _{CC} = 3.0V			10	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	V _{CC} ≤ 1.2V; V _O = 0.5V to V _{CC} ; V _I = GND or V _{CC} OE/OE = Don't care			1	±100	μA
I _{OZH}	3-State output High current	V _{CC} = 3.6V; V _O = 3.0V; V _I = V _{IL} or V _{IH}			0.5	5	μA
I _{OZL}	3-State output Low current	V _{CC} = 3.6V; V _O = 0.5V; V _I = V _{IL} or V _{IH}			0.5	-5	μA
I _{CCH}	Quiescent supply current	V _{CC} = 3.6V; Outputs High, V _I = GND or V _{CC} , I _O = 0			0.05	0.1	mA
I _{CCL}		V _{CC} = 3.6V; Outputs Low, V _I = GND or V _{CC} , I _O = 0			3.6	5	
I _{CCZ}		V _{CC} = 3.6V; Outputs Disabled; V _I = GND or V _{CC} , I _O = 0 ⁵			0.06	0.1	
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 3V to 3.6V; One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND			0.04	0.4	mA

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^\circ C$.
2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.
3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From $V_{CC} = 1.2V$ to $V_{CC} = 3.3V \pm 0.3V$ a transition time of 100 μ sec is permitted. This parameter is valid for $T_{amb} = 25^\circ C$ only.
4. Unused pins at V_{CC} or GND.
5. I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
6. This is the bus hold overdrive current required to force the input to the opposite logic state.

2.5V/3.3V 16-bit buffer/driver (3-State)

74ALVT16244

AC CHARACTERISTICS (3.3V $\pm$ 0.3V RANGE)GND = 0V; $t_R = t_F = 2.5\text{ns}$; $C_L = 50\text{pF}$; $R_L = 500\Omega$; $T_{\text{amb}} = -40^\circ\text{C}$ to $+85^\circ\text{C}$.

SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT
			V _{CC} = 3.3V ±0.3V			
			MIN	TYP ¹	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	0.8 0.8	1.5 1.5	2.4 2.5	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.0 0.5	2.3 1.8	3.8 2.9	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	1.5 1.5	2.7 2.3	4.2 3.6	ns

NOTE:1. All typical values are at $V_{CC} = 3.3\text{V}$ and $T_{\text{amb}} = 25^\circ\text{C}$.**DC ELECTRICAL CHARACTERISTICS (2.5V $\pm$ 0.2V RANGE)**

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS			UNIT
				Temp = -40°C to +85°C			
				MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	V _{CC} = 2.3V; I _{IK} = -18mA			-0.85	-1.2	V
V _{OH}	High-level output voltage	V _{CC} = 2.3 to 2.7V; I _{OH} = -100μA		V _{CC} -0.2	V _{CC}		V
		V _{CC} = 2.3V; I _{OH} = -8mA		1.8	2.5		
V _{OL}	Low-level output voltage	V _{CC} = 2.3V; I _{OL} = 100μA			0.07	0.2	
		V _{CC} = 2.3V; I _{OL} = 24mA			0.3	0.5	
I _I	Input leakage current	V _{CC} = 2.7V; V _I = V _{CC} or GND	Control pins		0.1	±1	μA
		V _{CC} = 0 or 2.7V; V _I = 5.5V			0.1	10	
		V _{CC} = 2.7V; V _I = V _{CC}	Data pins ⁴		0.1	1	
		V _{CC} = 2.7V; V _I = 0			0.1	-5	
I _{OFF}	Off current	V _{CC} = 0V; V _I or V _O = 0 to 4.5V			0.1	±100	μA
I _{HOLD}	Bus Hold current	V _{CC} = 2.3V; V _I = 0.7V			115		μA
	Data inputs ⁶	V _{CC} = 2.3V; V _I = 1.7V			-10		
I _{EX}	Current into an output in the High state when V _O > V _{CC}	V _O = 5.5V; V _{CC} = 2.3V			10	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	V _{CC} ≤ 1.2V; V _O = 0.5V to V _{CC} ; V _I = GND or V _{CC} ; OE/OE = Don't care			1	±100	μA
I _{OZH}	3-State output High current	V _{CC} = 2.7V; V _O = 2.3V; V _I = V _{IL} or V _{IH}			0.5	5	μA
I _{OZL}	3-State output Low current	V _{CC} = 2.7V; V _O = 0.5V; V _I = V _{IL} or V _{IH}			0.5	-5	μA
I _{CCH}	Quiescent supply current	V _{CC} = 2.7V; Outputs High, V _I = GND or V _{CC} , I _O = 0			0.04	0.1	mA
I _{CCL}		V _{CC} = 2.7V; Outputs Low, V _I = GND or V _{CC} , I _O = 0			2.5	4.5	
I _{CCZ}		V _{CC} = 2.7V; Outputs Disabled; V _I = GND or V _{CC} , I _O = 0 ⁵			0.04	0.1	
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 2.3V to 2.7V; One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND			0.04	0.4	mA

NOTES:

- All typical values are at $V_{CC} = 2.5\text{V}$ and $T_{\text{amb}} = 25^\circ\text{C}$.
- This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
- This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From $V_{CC} = 1.2\text{V}$ to $V_{CC} = 2.5\text{V} \pm 0.2\text{V}$ a transition time of 100 μsec is permitted. This parameter is valid for $T_{\text{amb}} = 25^\circ\text{C}$ only.
- Unused pins at V_{CC} or GND.
- I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
- Not guaranteed.

2.5V/3.3V 16-bit buffer/driver (3-State)

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AC CHARACTERISTICS (2.5V ± 0.2V RANGE)

GND = 0V; $t_R = t_F = 2.5\text{ns}$; $C_L = 50\text{pF}$; $R_L = 500\Omega$; $T_{\text{amb}} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$.

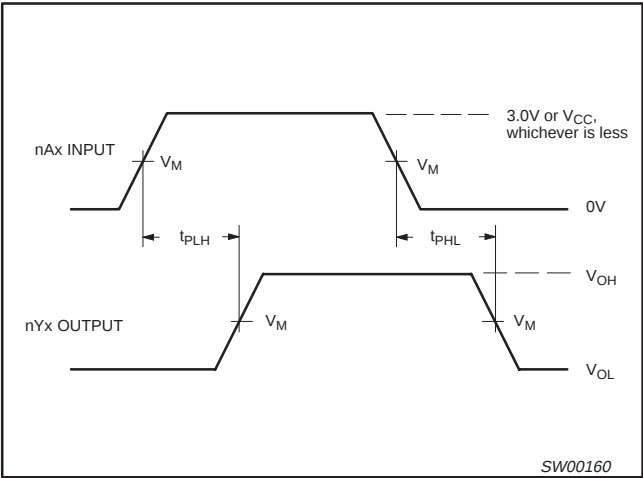
SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT
			V _{CC} = 2.5V ±0.2V			
			MIN	TYP ¹	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	1.0 1.0	1.8 1.9	3.0 3.5	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	2.0 1.5	3.1 2.5	5.9 4.7	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	1.5 1.0	2.7 2.0	4.4 3.4	ns

NOTE:

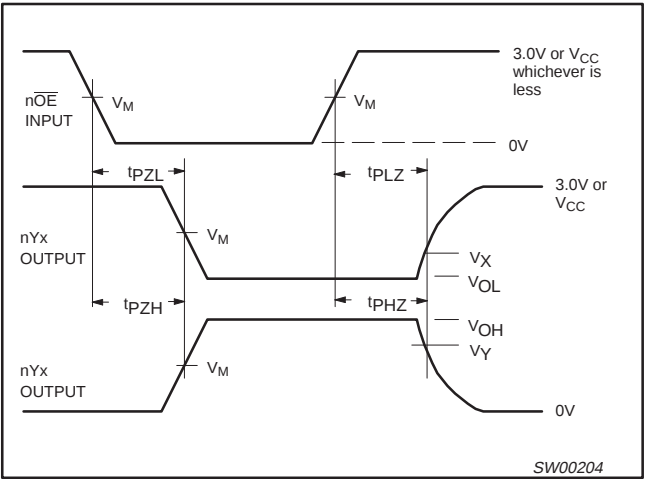
1. All typical values are at $V_{CC} = 2.5\text{V}$ and $T_{\text{amb}} = 25^{\circ}\text{C}$.

AC WAVEFORMS

$V_M = 1.5\text{V}$ at $V_{CC} \geq 3.0\text{V}$; $V_M = V_{CC}/2$ at $V_{CC} \leq 2.7\text{V}$
 $V_X = V_{OL} + 0.3\text{V}$ at $V_{CC} \geq 3.0\text{V}$; $V_X = V_{OL} + 0.15\text{V}$ at $V_{CC} \leq 2.7\text{V}$
 $V_Y = V_{OH} - 0.3\text{V}$ at $V_{CC} \geq 3.0\text{V}$; $V_Y = V_{OH} - 0.15\text{V}$ at $V_{CC} \leq 2.7\text{V}$



Waveform 1. Input (nAx) to Output (nYx) Propagation Delays

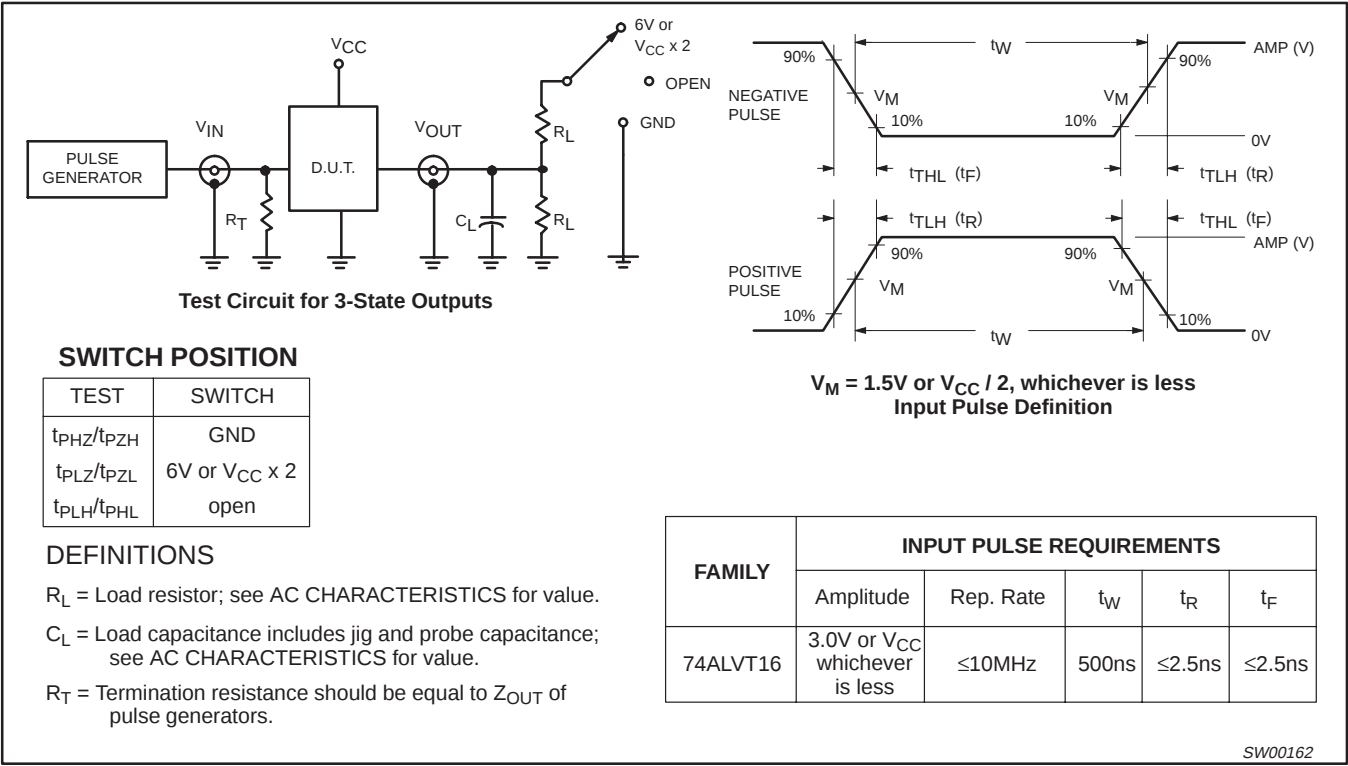


Waveform 2. 3-State Output Enable and Disable Times

2.5V/3.3V 16-bit buffer/driver (3-State)

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TEST CIRCUIT AND WAVEFORMS

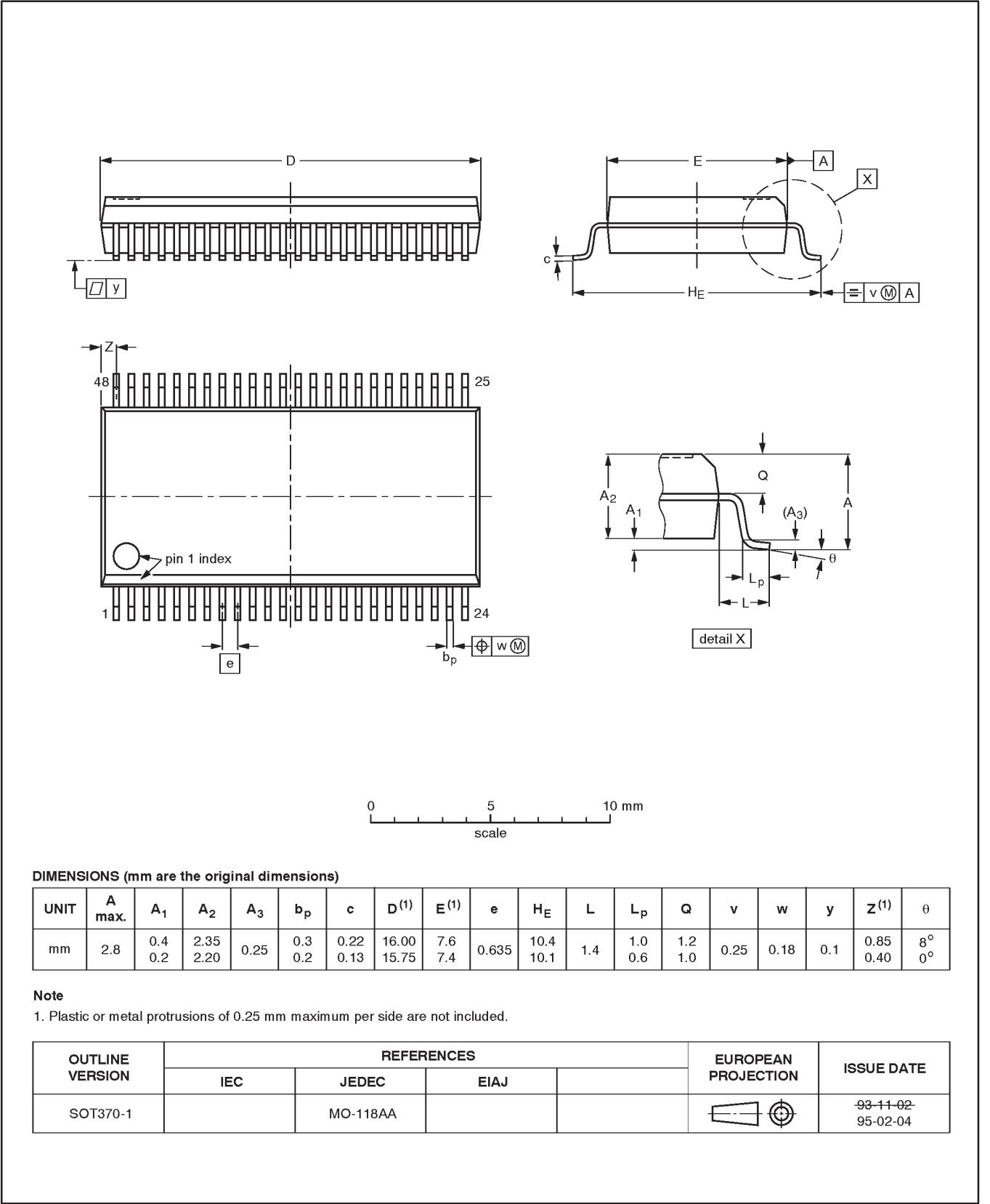


2.5V/3.3V 16-bit buffer/driver (3-State)

74ALVT16244

SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1

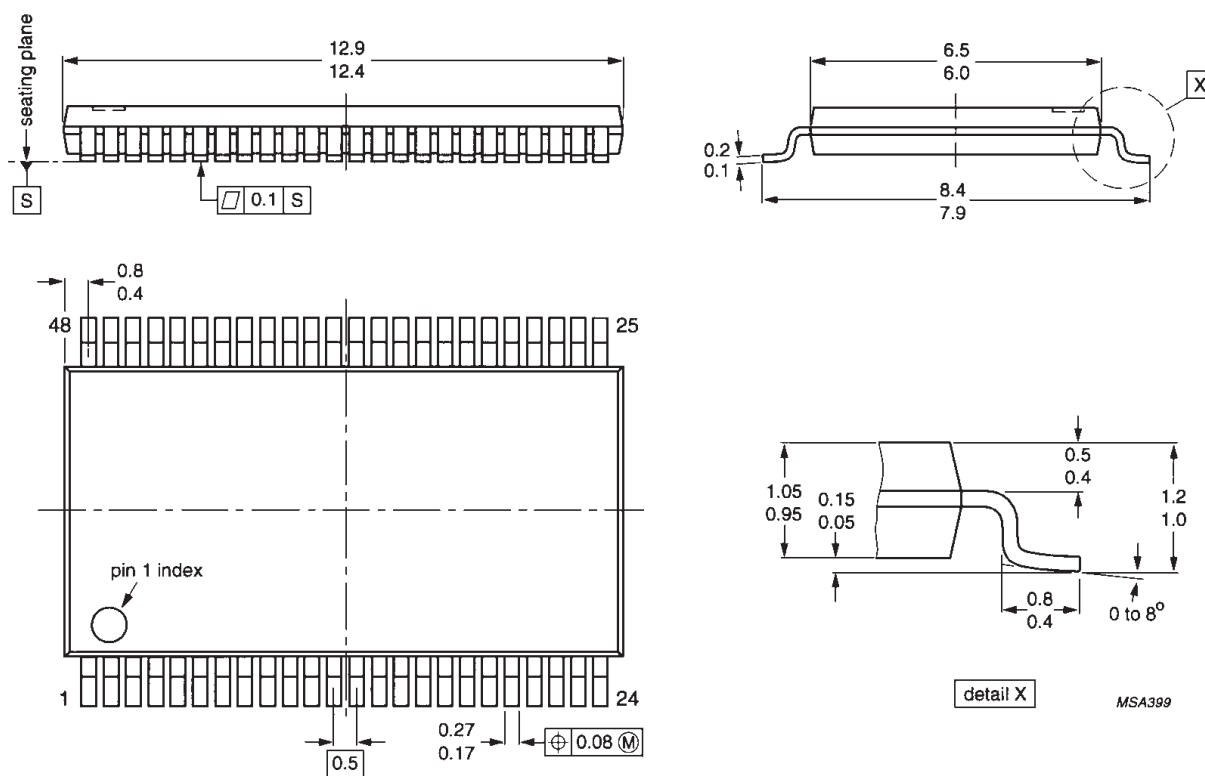


2.5V/3.3V 16-bit buffer/driver (3-State)

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TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm

SOT362-1



Dimensions in mm.

2.5V/3.3V 16-bit buffer/driver (3-State)

74ALVT16244

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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